

Trans MOSFET N-CH Si 60V 6A Automotive 6-Pin UDFN-B EP



Images are for reference only

[Inquiry](#)

Manufacturer: [Toshiba Semiconductor](#)

Package/Case: UDFN6B

Product Type: Thyristors

RoHS: RoHS Compliant/Lead free 

Lifecycle: Active

General Description

SSM6K341NU is a power MOSFET (Metal-Oxide-Semiconductor Field-Effect Transistor) designed for high-frequency switching applications. Here are some of its features:

Key Features

- Drain-Source Voltage (V_{dss}): 60V
- Continuous Drain Current (I_d): 13A
- Low on-state resistance (R_{ds(on)}): 11mΩ
- Fast switching speed
- Low gate charge
- Small package size: TSMT6

Application

- IRF6894MTRPBF
- SI7860DP-T1-GE3
- FDS4435BZ
- AOZ8804DI

Recommended For You

SSMBJ338R

Toshiba Semiconductor
SOT-23F

SSM6K403TU

Toshiba Semiconductor
UF6

SSM6N15FU

Toshiba Semiconductor
SOT-363

SSMBK127TU

Toshiba Semiconductor
SOT-323

SSM6N57NU

Toshiba Semiconductor
UDFN6

SSMBK339R

Toshiba Semiconductor
SOT-23F

SSM6K407TU

Toshiba Semiconductor

SOT-363

SSM3J372R

Toshiba Semiconductor

SOT-23F

SSM6L09FU

Toshiba Semiconductor

SOT-363

SSM6N17FU

Toshiba Semiconductor

SOT-363

SSM6L35FE

Toshiba Semiconductor

ES6

SSM6L35FU

Toshiba Semiconductor

SOT-363

SSM6N15AFU

Toshiba Semiconductor

SOT-363

SSM6N15AFE

Toshiba Semiconductor

SOT-363

SSM6N36FE

Toshiba Semiconductor

SOT563